

#3/A  
T. Young  
4-21-99

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Yasunori INOUE

Serial Number: [Division of 08/806,425]

Filed: January 11, 1999

For: SEMICONDUCTOR DEVICE INCLUDING AN INSULATION FILM ON  
A CONDUCTIVE LAYER AND MANUFACTURING METHOD THEREOF

**PRELIMINARY AMENDMENT**

Assistant Commissioner for Patents  
Washington, D.C. 20231

January 11, 1999

Dear Sir:

Prior to action on the above-identified application, please amend the same as follows:

**IN THE SPECIFICATION:**

Change the title to read --METHOD OF MANUFACTURING A SEMICONDUCTOR  
DEVICE--.

Page 2, line 9: after "which" insert --a--;

line 12: after "having" insert --a--.

Page 9, delete lines 23-25 and substitute therefor:

a' Fig. 16 is a sectional view of the structure of a semiconductor device where a  
spacer is omitted from the structure shown in Fig. 1 in order to describe effects  
of the spacer.